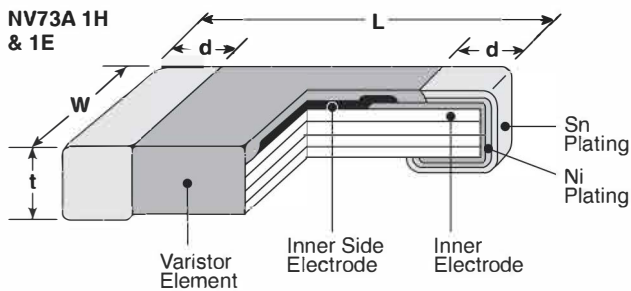


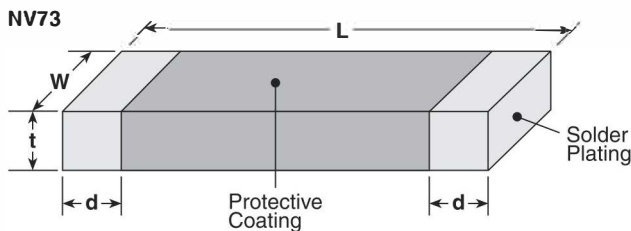
features

- Multilayer structure
- High surge current
- Protector against static electricity, switching and incoming surges
- Suitable for both flow and reflow soldering
- Products with lead-free terminations meet EU RoHS requirements. Pb located in glass material, electrode and varistor element is exempt per Annex 1, exemption 5 of EU directive 2005/95/EC

dimensions and construction



Type (Inch Size Code)	Dimensions inches (mm)			
	L	W	t	d
2E (1210)	.126±.008 (3.2±0.2)	.098±.008 (2.5±0.2)	.059 max. (1.5 max.)	.020±.008 (0.5±0.2)
2J (1812)	.177±.008 (4.5±0.2)	.126±.008 (3.2±0.2)	.079 max. (2.0 max.)	.020 ^{+0.012} _{-.004} (0.5 ^{+0.3} _{-.01})
2L (2220)	.224±.008 (5.7±0.2)	.197±.008 (5.0±0.2)	.098 max. (2.5 max.)	.020 ^{+0.001} _{-.004} (0.5 ^{+0.3} _{-.01})
C2L (2220)	.232±.008 (5.9±0.2)	.201±.008 (5.1±0.2)	.106 max. (2.7 max.)	.028 ^{+0.016} _{-.012} (0.7 ^{+0.4} _{-.03})



ordering information

NV73	A		2J	T	TE	12
Type	Energy Code	Capacitance Type	Size	Termination Material	Packaging	Varistor Voltage
	A B C	Blank: Standard	2E: 1210 2J: 1812 2L: 2220	T: Sn	TE: 7" embossed plastic (2J, 2L: 1,000 pieces/reel 2E: 2,000 pieces/reel)	8: 8V 12: 12V 120: 120V

applications and ratings

Part Designation	Varistor Voltage Vc	Maximum Allowable Voltage		Clamping Voltage			Maximum Energy E (J) (100 times)	Maximum Peak Current IP (A) (100 times)	Operating Temp. T _{opt} (°C)	Storage Temp. T _{stg} (°C)	
		Ic = 1mA (V)	a.c rms (V)	d.c (V)	V _{2.5A}	V _{5A}					V _{10A}
NV73A2ETTE15	12.8 - 17.3	8.0	11.0	30	—	—	1.0	400	-50°C to +125°C	-50°C to +150°C	
NV73A2ETTE18	15.3 - 20.7	11.0	14.0	34	—	—	1.2				
NV73A2ETTE22	19.8 - 24.2	12.0	16.5	39	—	—	1.4				
NV73A2ETTE24	21.6 - 26.4	14.0	18.0	39	—	—	1.4				
NV73A2ETTE27	24.3 - 29.7	17.0	22.0	44	—	—	1.7				
NV73A2ETTE33	29.7 - 36.3	20.0	26.0	54	—	—	1.9				
NV73A2ETTE39	35.1 - 42.9	25.0	30.0	65	—	—	1.7				
NV73A2ETTE47	42.3 - 51.7	30.0	38.0	77	—	—	2.0				
NV73A2ETTE56	50.4 - 61.6	35.0	45.0	90	—	—	2.0				
NV73A2ETTE82	73.8 - 90.2	50.0	65.0	135	—	—	1.2				250
NV73A2ETTE100	90.0 - 110.0	60.0	85.0	165	—	—	1.4				200
NV73A2ETTE110	99.0 - 121.0	70.0	90.0	180	—	—	1.4				
NV73A2JTTE12	10.2 - 13.8	6.0	9.0	—	27	—	0.9	500			
NV73A2JTTE15	12.8 - 17.3	8.0	11.0	—	32	—	1.2				
NV73A2JTTE18	16.2 - 19.8	11.0	14.0	—	35	—	1.4				
NV73A2JTTE22	19.8 - 24.2	12.0	16.5	—	41	—	1.6				
NV73A2JTTE24	21.6 - 26.4	14.0	18.0	—	44	—	1.7				
NV73A2JTTE27	24.3 - 29.7	17.0	22.0	—	49	—	2.0				
NV73A2JTTE33	29.7 - 36.3	20.0	26.0	—	54	—	2.5				
NV73A2JTTE39	35.1 - 42.9	25.0	30.0	—	65	—	2.9				
NV73A2JTTE47	42.3 - 51.7	30.0	38.0	—	77	—	3.5				
NV73A2JTTE56	50.4 - 61.6	35.0	45.0	—	90	—	4.2				
NV73A2JTTE68	61.2 - 74.8	40.0	56.0	—	110	—	4.8				
NV73A2JTTE82	73.8 - 90.2	50.0	65.0	—	135	—	4.5		400		
NV73A2JTTE100	90 - 110	60.0	85.0	—	165	—	5.8				
NV73A2JTTE110	99 - 121	70.0	90.0	—	180	—	5.8				
NV73A2JTTE150	135 - 165	95.0	127.0	—	248	—	5.8		300		
NV73B2JTTE15	12.8 - 17.3	8.0	11.0	—	32	—	1.8	800			
NV73B2JTTE18	15.3 - 20.7	11.0	14.0	—	35	—	1.9				
NV73B2JTTE22	19.8 - 24.2	12.0	16.5	—	41	—	2.3				
NV73B2JTTE24	21.6 - 26.4	14.0	18.0	—	44	—	2.3				
NV73B2JTTE27	24.3 - 29.7	17.0	22.0	—	49	—	2.7				
NV73B2JTTE33	29.7 - 36.3	20.0	26.0	—	54	—	3.0				

vertical text: circuit protection

applications and ratings (continued)

Part Designation	Varistor Voltage Vc	Maximum Allowable Voltage		Clamping Voltage			Maximum Energy E (J) (100 times)	Maximum Peak Current I _p (A) (100 times)	Operating Temp. T _{opt} (°C)	Storage Temp. T _{stg} (°C)	
		I _c = 1mA (V)	a.c rms (V)	d.c (V)	V _{2.5A}	V _{5A}					V _{10A}
NV73B2JTTE39	35.1 - 42.9	25.0	30.0	—	65	—	3.7	800	-50°C to +125°C	-50°C to +150°C	
NV73B2JTTE47	42.3 - 51.7	30.0	38.0	—	77	—	4.2				
NV73B2JTTE56	50.4 - 61.6	35.0	45.0	—	90	—	4.2				
NV73A2LTTE12	10.2 - 13.8	6.0	9.0	—	—	28	1.9	1000			
NV73A2LTTE15	12.8 - 17.3	8.0	11.0	—	—	33	2.3				
NV73A2LTTE18	16.2 - 19.8	11.0	14.0	—	—	36	2.7				
NV73A2LTTE22	19.8 - 24.2	12.0	16.5	—	—	41	2.9				
NV73A2LTTE24	21.6 - 26.4	14.0	18.0	—	—	45	3.1				
NV73A2LTTE27	24.3 - 29.7	17.0	22.0	—	—	48	3.8				
NV73A2LTTE33	29.7 - 36.3	20.0	26.0	—	—	57	4.3				
NV73A2LTTE39	35.1 - 42.9	25.0	30.0	—	—	65	5.5				
NV73A2LTTE47	42.3 - 51.7	30.0	38.0	—	—	77	6.3				
NV73A2LTTE56	50.4 - 61.6	35.0	45.0	—	—	90	7.7				
NV73A2LTTE68	61.2 - 74.8	40.0	56.0	—	—	110	8.8				
NV73A2LTTE100	90 - 110	60.0	85.0	—	—	165	6.8				
NV73A2LTTE110	99 - 121	70.0	90.0	—	—	180	6.8				
NV73B2LTTE15	12.8 - 17.3	8.0	11.0	—	—	33	4.2				1200
NV73B2LTTE18	15.3 - 20.7	11.0	14.0	—	—	36	5.4				
NV73B2LTTE22	19.8 - 24.2	12.0	16.5	—	—	41	5.8				
NV73B2LTTE24	21.6 - 26.4	14.0	18.0	—	—	45	5.8				
NV73B2LTTE27	24.3 - 29.7	17.0	22.0	—	—	48	7.2				
NV73B2LTTE33	29.7 - 36.3	20.0	26.0	—	—	57	7.8				
NV73B2LTTE39	35.1 - 42.9	25.0	30.0	—	—	65	9.6				
NV73B2LTTE47	42.3 - 51.7	30.0	38.0	—	—	77	12.0				
NV73B2LTTE56	50.4 - 61.6	35.0	45.0	—	—	90	7.7				
NV73B2LTTE82	73.8 - 90.2	50.0	65.0	—	—	135	5.6	1000			
NV73C2LTTE39	35.1 - 42.9	25.0	30.0	—	—	65	5.6 (1 time)	2500 (1 time)			
NV73C2LTTE82	73.8 - 90.2	50.0	65.0	—	—	135	14 (1 time)	4500 (1 time)			

Maximum allowable voltage - the maximum sinusoidal RMS voltage or maximum DC voltage which can be applied continuously
 E: Maximum energy - the maximum energy within the varistor voltage change of ±10% when a single impulse of 2m sec. is applied
 I_p: Maximum peak current - the maximum peak current within the varistor voltage change of ±10% when a single standard impulse of 8/20μ sec. is applied two times with an interval of 5 min.
 T_{opt}: Operating temperature - Ambient temperature range when the device is operating
 T_{stg}: Storage temperature - Temperature range without causing the device any failure

environmental applications

Performance Characteristics

Parameter	Requirement Δ V±%	Test Method
Varistor Voltage	Within specified tolerance	Voltage between terminals when 1mA is flowed
Solderability	95% coverage minimum	235°C ± 5°C, 4 seconds ± 1 second
Resistance to Solder Heat	±10%	260°C ± 5°C, 4 seconds ± 1 second
Rapid Change of Temperature	±10%	-40°C (30 minutes), +125°C (30 minutes), 30 cycles; 5 cycles
Maximum Peak Current	±10%	A single standard impulse of 8/20μ seconds, 100 pulse, 30 second interval
Maximum Energy	±10%	A single standard impulse of 10/1000μs, 100pulse, 90 second interval
High Temperature Life with d.c. Bias	±10%	125°C ± 5°C, 1000h, Load: Maximum allowable circuit voltage (d.c.)
Low Temperature Life with d.c. Bias	±10%	-50°C ± 5°C, 1000h, Load: Maximum allowable circuit voltage (d.c.)
High Temperature Life with a.c. Bias**	±10%	85°C ± 5°C, 1000h, Load: Maximum allowable circuit voltage (V _{a.c.r.m.s.})
High Temperature & High Humidity Life with d.c. Bias	±10%	40°C ± 5°C, 95% RH, 500h, Load: Maximum allowable voltage (d.c.)
High Temperature Storage Life	±10%	150°C ± 5°C, 1000h
Low Temperature Storage Life	±10%	-50°C ± 5°C, 1000h

For Voltage Current Curves Graphs see Environmental Applications. Additional environmental applications can also be found at www.koaspeer.com

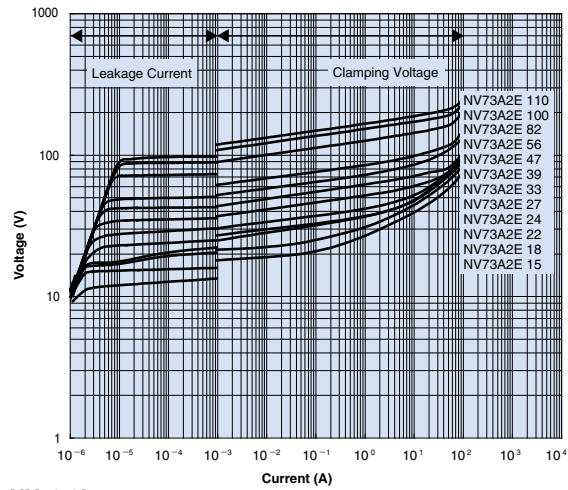
Specifications given herein may be changed at any time without prior notice. Please confirm technical specifications before you order and/or use.

10/19/23

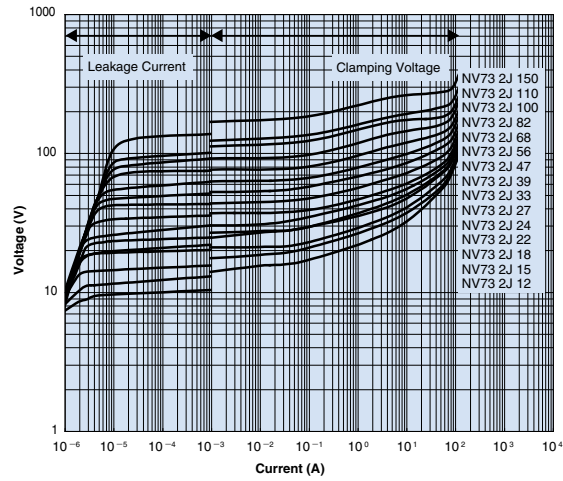
environmental applications (continued)

Voltage-Current Curves (Ta = 25°C)

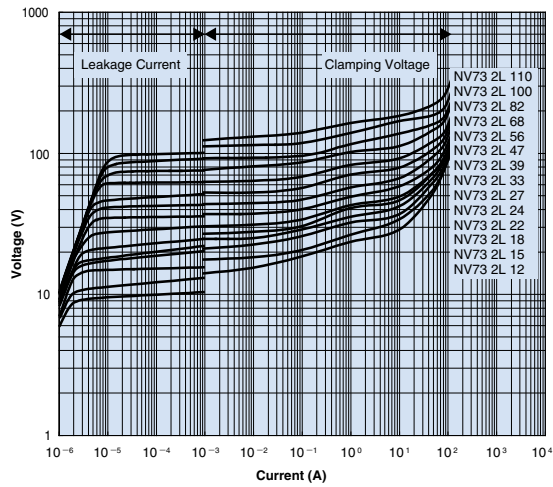
NV73 2E



NV73 2J



NV73 2L



circuit protection